



T-52-09

74ACQ241 • 54ACTQ/74ACTQ241

Quiet Series Octal Buffer/Line Driver

with TRI-STATE® Outputs

General Description

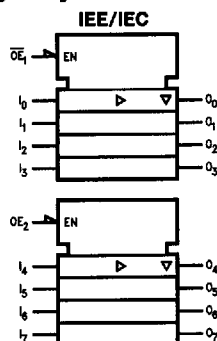
The 'ACQ/'ACTQ241 is an octal buffer and line driver designed to be employed as a memory address driver, clock driver and bus oriented transmitter or receiver which provides improved PC board density. The ACQ/ACTQ utilizes NSC Quiet Series technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series™ features GTOTM output control and undershoot corrector in addition to a split ground bus for superior performance.

Features

- I_{CC} and I_{OZ} reduced by 50%
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Improved latch-up immunity
- TRI-STATE® outputs drive bus lines or buffer memory address registers
- Outputs source/sink 24 mA
- Faster prop delays than the standard 'AC/'ACT241
- 4 kV minimum ESD immunity ('ACTQ)
- Standard Military Drawing (SMD)
— 'ACTQ241: 5962-92185

Ordering Code: See Section 8

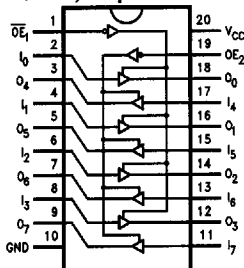
Logic Symbol



TL/F/10642-1

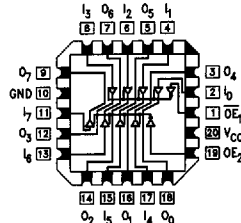
Connection Diagrams

Pin Assignment
for DIP, Flatpak and SOIC



TL/F/10642-2

Pin Assignment
for LCC



TL/F/10642-3

Truth Tables

Pin Names	Description
$\overline{OE}_1, \overline{OE}_2$	TRI-STATE Output Enable Inputs
I_0-I_7	Inputs
O_0-O_7	Outputs

Inputs		Outputs (Pins 12, 14, 16, 18)
$\overline{OE}_1$	I_n	
L	L	L
L	H	H
H	X	Z

Inputs		Outputs (Pins 3, 5, 7, 9)
$\overline{OE}_2$	I_n	
H	L	L
H	H	H
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Q241

Absolute Maximum Rating (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (V _{CC})	-0.5V to +7.0V
DC Input Diode Current (I _{IK})	
V _I = -0.5V	-20 mA
V _I = V _{CC} + 0.5V	+20 mA
DC Input Voltage (V _I)	-0.5V to V _{CC} + 0.5V
DC Output Diode Current (I _{OK})	
V _O = -0.5V	-20 mA
V _O = V _{CC} + 0.5V	+20 mA
DC Output Voltage (V _O)	-0.5V to V _{CC} + 0.5V
DC Output Source or Sink Current (I _O)	±50 mA
DC V _{CC} or Ground Current per Output Pin (I _{CC} or I _{GND})	±50 mA
Storage Temperature (T _{STG})	-65°C to +150°C
DC Latch-Up Source or Sink Current	±300 mA
Junction Temperature (T _J)	
CDIP	175°C
PDIP	140°C

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. National does not recommend operation of FACT circuits outside databook specifications.

Recommended Operating Conditions

Supply Voltage (V _{CC})	2.0V to 6.0V
'ACQ	4.5V to 5.5V
'ACTQ	
Input Voltage (V _I)	0V to V _{CC}
Output Voltage (V _O)	0V to V _{CC}
Operating Temperature (T _A)	
74ACQ/ACTQ	-40°C to +85°C
54ACTQ	-55°C to +125°C
Minimum Input Edge Rate ΔV/Δt	
'ACQ Devices	
V _{IN} from 30% to 70% of V _{CC}	
V _{CC} @ 3.0V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate ΔV/Δt	
'ACTQ Devices	
V _{IN} from 0.8V to 2.0V	
V _{CC} @ 4.5V, 5.5V	125 mV/ns

Note: All commercial packaging is not recommended for applications requiring greater than 2000 temperature cycles from -40°C to +125°C.

DC Electrical Characteristics for 'ACQ Family Devices

Symbol	Parameter	V _{CC} (V)	74ACQ		74ACQ		Units	Conditions
			T _A = +25°C		T _A = -40°C to +85°C			
			Typ	Guaranteed Limits				
V _{IH}	Minimum High Level Input Voltage	3.0	1.5	2.1	2.1		V	V _{OUT} = 0.1V or V _{CC} - 0.1V
		4.5	2.25	3.15	3.15			
		5.5	2.75	3.85	3.85			
V _{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.9	0.9		V	V _{OUT} = 0.1V or V _{CC} - 0.1V
		4.5	2.25	1.35	1.35			
		5.5	2.75	1.65	1.65			
V _{OH}	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9		V	I _{OUT} = -50 μA
		4.5	4.49	4.4	4.4			
		5.5	5.49	5.4	5.4			
		3.0		2.56	2.46		V	*V _{IN} = V _{IL} or V _{IH} -12 mA I _{OH} -24 mA -24 mA
		4.5		3.86	3.76			
		5.5		4.86	4.76			
V _{OL}	Maximum Low Level Output Voltage	3.0	0.002	0.1	0.1		V	I _{OUT} = 50 μA
		4.5	0.001	0.1	0.1			
		5.5	0.001	0.1	0.1			
		3.0		0.36	0.44		V	*V _{IN} = V _{IL} or V _{IH} 12 mA I _{OL} 24 mA 24 mA
		4.5		0.36	0.44			
		5.5		0.36	0.44			
I _{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0		μA	V _I = V _{CC} , GND (Note 1)

*All outputs loaded; thresholds on input associated with output under test.

Q241

DC Electrical Characteristics for 'ACQ Family Devices (Continued)

Symbol	Parameter	V _{CC} (V)	74ACQ		74ACQ	Units	Conditions
			T _A = +25°C		T _A = -40°C to +85°C		
			Typ	Guaranteed Limits			
I _{OLD}	†Minimum Dynamic Output Current	5.5			75	mA	V _{OLD} = 1.65V Max
I _{OHD}		5.5			-75	mA	V _{OHD} = 3.85V Min
I _{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V _{IN} = V _{CC} or GND (Note 1)
I _{OZ}	Maximum TRI-STATE Leakage Current	5.5		±0.25	±2.5	μA	V _I (OE) = V _{IL} , V _{IH} V _I = V _{CC} , GND V _O = V _{CC} , GND
V _{OLP}	Quiet Output Maximum Dynamic V _{OL}	5.0	1.1	1.5		V	Figures 2-12, 13 (Notes 2, 3)
V _{OLV}	Quiet Output Minimum Dynamic V _{OL}	5.0	-0.6	-1.2		V	Figures 2-12, 13 (Notes 2, 3)
V _{IHD}	Minimum High Level Dynamic Input Voltage	5.0	3.1	3.5		V	(Notes 2, 4)
V _{ILD}	Maximum Low Level Dynamic Input Voltage	5.0	1.9	1.5		V	(Notes 2, 4)

† Maximum test duration 2.0 ms, one output loaded at a time.

Note 1: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

Note 2: Plastic DIP package.

Note 3: Max number of outputs defined as (n). Data inputs are driven 0V to 5V. One output @ GND.

Note 4: Max number of Data Inputs (n) switching, n-1 Inputs switching 0V to 5V ('ACQ). Input-under-test switching: 5V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

DC Electrical Characteristics for 'ACTQ Family Devices

Symbol	Parameter	V _{CC} (V)	74ACTQ		54ACTQ		74ACTQ		Units	Conditions
			T _A = +25°C		T _A = -55°C to +125°C		T _A = -40°C to +85°C			
			Typ	Guaranteed Limits						
V _{IH}	Minimum High Level Input Voltage	4.5	1.5	2.0	2.0		2.0		V	V _{OUT} = 0.1V or V _{CC} - 0.1V
		5.5	1.5	2.0	2.0		2.0			
V _{IL}	Maximum Low Level Input Voltage	4.5	1.5	0.8	0.8		0.8		V	V _{OUT} = 0.1V or V _{CC} - 0.1V
		5.5	1.5	0.8	0.8		0.8			
V _{OH}	Minimum High Level Output Voltage	4.5	4.49	4.4	4.4		4.4		V	I _{OUT} = -50 μA
		5.5	5.49	5.4	5.4		5.4			
		4.5		3.86	3.70		3.76		V	*V _{IN} = V _{IL} or V _{IH} I _{OH} = -24 mA -24 mA
		5.5		4.86	4.70		4.76			
V _{OL}	Maximum Low Level Output Voltage	4.5	0.001	0.1	0.1		0.1		V	I _{OUT} = 50 μA
		5.5	0.001	0.1	0.1		0.1			
		4.5		0.36	0.50		0.44		V	*V _{IN} = V _{IL} or V _{IH} I _{OL} = 24 mA 24 mA
		5.5		0.36	0.50		0.44			
I _{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0		±1.0		μA	V _I = V _{CC} , GND

*All outputs loaded; thresholds on input associated with output under test.

DC Electrical Characteristics for 'ACTQ Family Devices (Continued)

Symbol	Parameter	V _{CC} (V)	74ACTQ		54ACTQ		74ACTQ		Units	Conditions
			T _A = +25°C		T _A = −55°C to +125°C		T _A = −40°C to +85°C			
			Typ	Guaranteed Limits						
I _{OZ}	Maximum TRI-STATE Leakage Current	5.5		±0.25	±5.0	±2.5		μA	V _I = V _{IL} , V _{IH} V _O = V _{CC} , GND	
I _{OCT}	Maximum I _{CC} /Input	5.5	0.6		1.6	1.5		mA	V _I = V _{CC} − 2.1V	
I _{OLD}	†Minimum Dynamic Output Current	5.5			50	75		mA	V _{OLD} = 1.65V Max	
I _{OHD}		5.5			−50	−75		mA	V _{OHD} = 3.85V Min	
I _{CC}	Maximum Quiescent Supply Current	5.5		4.0	80.0	40.0		μA	V _{IN} = V _{CC} or GND (Note 1)	
V _{OLP}	Quiet Output Maximum Dynamic V _{OL}	5.0	1.1	1.5				V	Figures 2-12, 13 (Notes 2, 3)	
V _{OLV}	Quiet Output Minimum Dynamic V _{OL}	5.0	−0.6	−1.2				V	Figures 2-12, 13 (Notes 2, 3)	
V _{IHD}	Minimum High Level Dynamic Input Voltage	5.0	1.9	2.2				V	(Notes 2, 4)	
V _{ILD}	Maximum Low Level Dynamic Input Voltage	5.0	1.2	0.8				V	(Notes 2, 4)	

†Maximum test duration 2.0 ms, one output loaded at a time.

Note 1: I_{CC} for 54ACTQ @ 25°C is identical to 74ACTQ @ 25°C.

Note 2: Plastic DIP package.

Note 3: Max number of outputs defined as (n). Data Inputs are driven 0V to 3V. One output @ GND.

Note 4: Max number of Data Inputs (n) switching. n-1 Inputs switching 0V to 3V (†ACTQ). Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics: See Section 2 for Waveforms

Symbol	Parameter	V _{CC} * (V)	74ACQ			74ACQ		Units	Fig. No.
			T _A = +25°C C _L = 50 pF			T _A = -40°C to +85°C C _L = 50 pF			
			Min	Typ	Max	Min	Max		
t _{PHL} , t _{PLH}	Propagation Delay Data to Output	3.3 5.0	2.0 1.5	6.5 4.5	9.0 6.0	2.0 1.5	9.5 6.5	ns	2-3, 4
t _{PZL} , t _{PZH}	Output Enable Time	3.3 5.0	2.5 1.5	8.0 5.5	13.0 8.5	2.5 1.5	13.5 9.0	ns	2-5, 6
t _{PHZ} , t _{PLZ}	Output Disable Time	3.3 5.0	1.0 1.0	8.5 5.5	14.5 9.5	1.0 1.0	15.0 10.0	ns	2-5, 6
t _{OSHL} , t _{OSLH}	Output to Output Skew **Data to Output	3.3 5.0		1.0 0.5	1.5 1.0		1.5 1.0	ns	

*Voltage Range 5.0 is 5.0V ±0.5V.

Voltage Range 3.3 is 3.3V ±0.3V.

**Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSH}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

AC Electrical Characteristics: See Section 2 for Waveforms

Symbol	Parameter	V _{CC} * (V)	74ACTQ			54ACTQ		74ACTQ		Units	Fig. No.
			T _A = +25°C C _L = 50 pF			T _A = -55°C to +125°C C _L = 50 pF		T _A = -40°C to +85°C C _L = 50 pF			
			Min	Typ	Max	Min	Max	Min	Max		
t _{PHL} , t _{PLH}	Propagation Delay Data to Output	5.0	1.5	5.0	6.5	1.5	8.0	1.5	7.0	ns	2-3, 4
t _{PZL} , t _{PZH}	Output Enable Time	5.0	1.5	6.5	9.0	1.5	10.5	1.5	9.5	ns	2-5, 6
t _{PHZ} , t _{PLZ}	Output Disable Time	5.0	1.0	7.0	10.0	1.5	9.5	1.0	10.5	ns	2-5, 6
t _{OSHL} , t _{OSLH}	Output to Output Skew **Data to Output	5.0		0.5	1.0				1.0	ns	

*Voltage Range 5.0 is 5.0V ±0.5V.

Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.Capacitance**

Symbol	Parameter	Typ	Units	Conditions
C _{IN}	Input Capacitance	4.5	pF	V _{CC} = OPEN
C _{PD}	Power Dissipation Capacitance	70	pF	V _{CC} = 5.0V